

DESCRIPTION

The UMX5601™ PIN diode series was designed to provide ultra low magnetic PIN diodes for in bore surface coil applications associated with higher field strength (3T and greater) MR scanners. These PIN diodes produce the minimum artifacts (magnetic field distortions) available in the industry, today. The diodes have been tested in magnetic fields of ±7 Tesla.

The UMX5601 PIN diodes have a magnetic moment at 7 T of 4E-8 (JT).

The diodes are offered in a surface mount package. The SM package utilizes a round end cap to mark the anode. The cathode is square. The fully passivated PIN diode chip is full face metallurgically bonded to shortened high conductive pins for lower thermal and electrical resistances. The PIN diodes feature low forward bias resistance and high zero bias impedance. The UMX5601 PIN diodes are characterized at 64, 128, and 300 MHz. The UMX5601SM meets RoHS requirements per EU Directive 2002/95/EC.

IMPORTANT: For the most current data, consult our website: www.MICROSEMI.com

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	100	V
Working Peak Reverse Voltage	V_{RWM}	100	
DC Blocking Voltage	V_R	100	
RMS Reverse Voltage	$V_{R(RMS)}$	75	V
Storage Temperature	T stg	-65 to +175	°C
Operating Temperature Non-Repetitive Peak	T op	-65 to +150	°C

THERMAL CHARACTERISTICS (UNLESS OTHERWISE SPECIFIED)

Thermal Resistance	Symbol	Value	Unit
UMX5601SM	θ	2	°C/Watt



KEY FEATURES

- Ultra low magnetic construction
- SOGO passivated chip
- Thermally matched configuration
- RoHS compliant ¹
- Low capacitance at 0 V bias
- Low conductance at 0 V bias
- Metallurgical bond
- Fused-in-glass construction
- Non cavity design
- Available in surface mount package.
- Compatible with automatic insertion equipment

1- These devices are supplied with Silver terminations. Other terminal finishes may be available on request. Consult factory for details.

APPLICATIONS/BENEFITS

- High B Field (3T+) in bore
- APPLICATIONS:**
- Active or semi-active (not passive)
 - MR blocking circuits
 - MR detuning circuits
 - MR disable circuits
 - MR receiver protector circuits



UMX5601

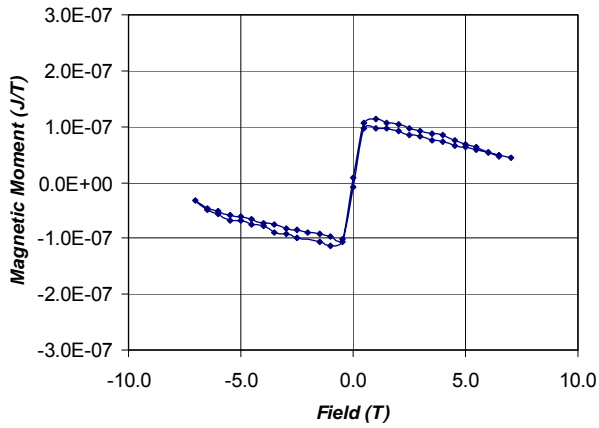
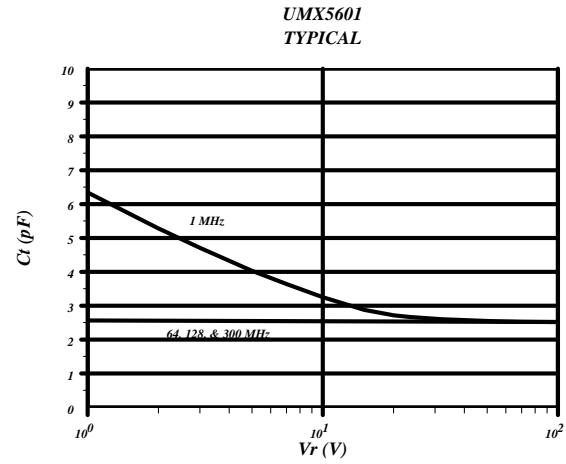
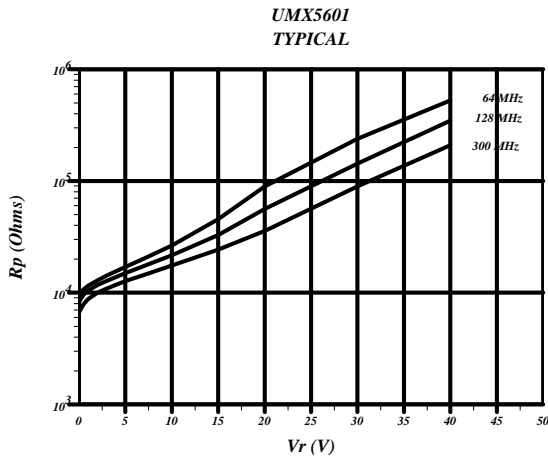
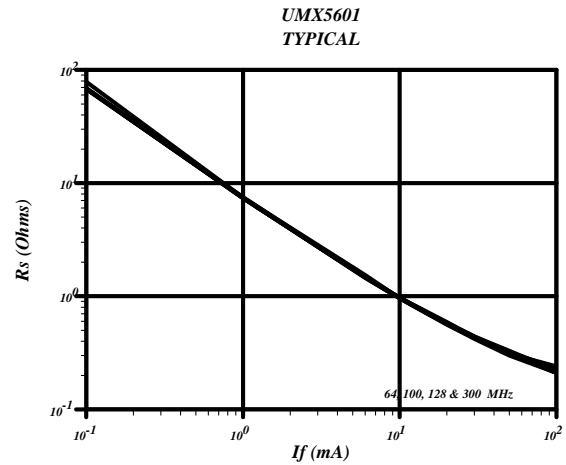
ULTRA LOW MAGNETIC MOMENT PIN DIODE FOR MRI APPLICATIONS

RoHS COMPLIANT

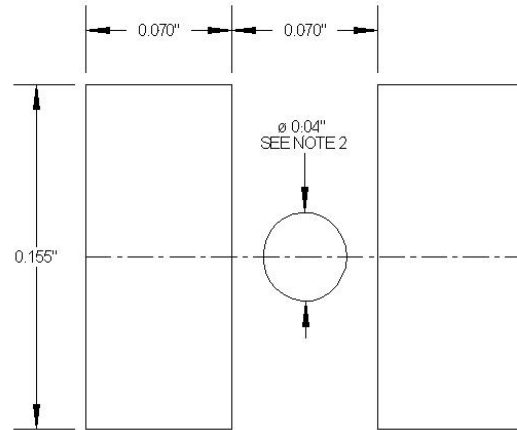
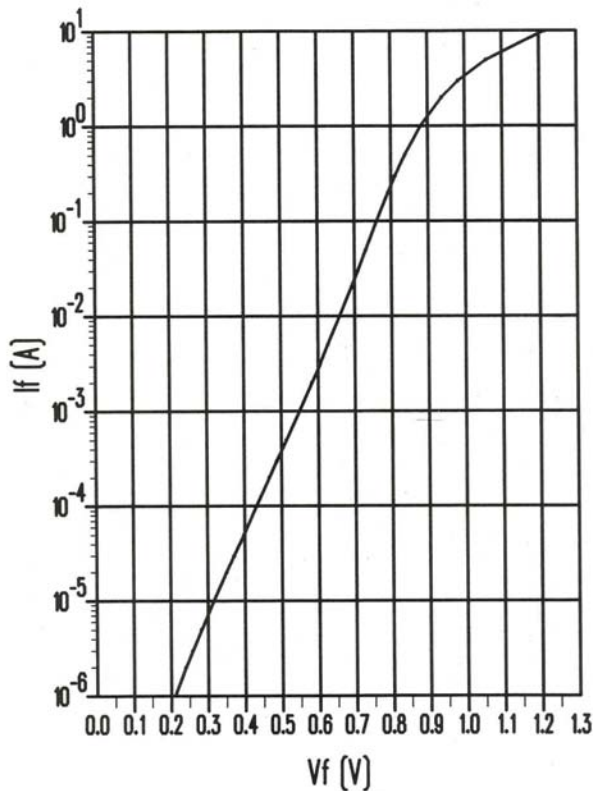


ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ.	Max	Units
Forward Voltage	V_F	$I_F = 100 \text{ mA}$		0.75	1.0	V
Reverse Break Down Voltage	V_{BR}	$I_R = 10 \text{ uA}$	100			V
Reverse Current	I_R	$V_R = 100 \text{ V}$			10	uA
Inductance	LS			900		pH
Magnetic moment	m	@ 7T @ 1T		4E-8 1E-7		J/T J/T
Mass Susceptibility	χ_p	@ 7T @ 1T		-3.3E-11 6.5E-10		m³/kg m³/kg
Volume Susceptibility	χ	>1T to 7T <1T		-3.1E-7 5.9E-6		SI SI
Capacitance	C_T	$V_R = 0 \text{ V}, F = 1 \text{ MHz}$		9	10	pF
		$V_R = 50 \text{ V}, F = 1 \text{ MHz}$		2.6	3.0	
Parallel Resistance	R_P	$V_R = 0 \text{ V}, F = 64 \text{ MHz}$	5	9		kΩ
		$V_R = 30 \text{ V}, F = 64 \text{ MHz}$	100	250		
Series Resistance	R_S	$I_f = 100 \text{ mA}, F = 64 \text{ MHz}$		0.3	0.5	Ω
Lifetime	τ	$I_f = 10 \text{ mA}$	5	10		us

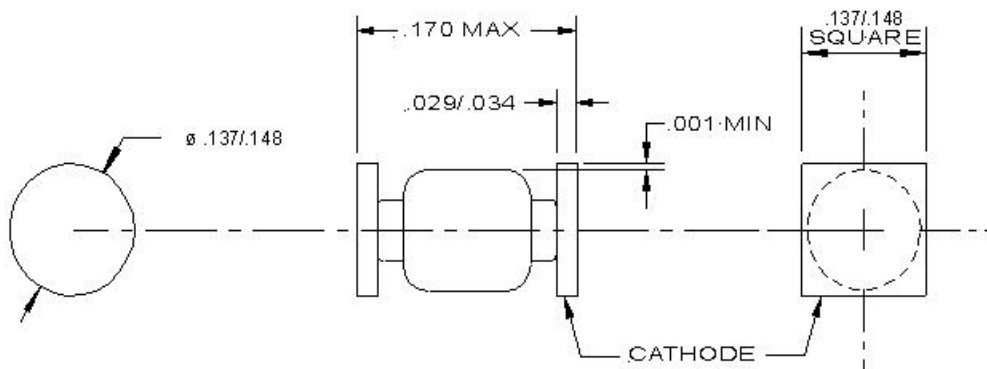
MAGNETIC MOMENT VS FIELD

C-V CURVES

RP - PARALLEL RESISTANCE

RS VS IF


VF VS IF
SM STYLE SOLDER FOOTPRINT

 UMX5601
TYPICAL

NOTES:

1. These dimensions will match the terminals and provide for additional solder fillets at the outboard ends at least as wide as the terminals themselves, assuming accuracy of device placement within .005 inches.
2. If the mounting method chosen requires use of an adhesive separate from the solder compound, a round (or square) spot of cement as shown should be centrally located.

Dimensions shown are in inches

"SM" STYLE PACKAGE OUTLINE


DIMENSIONS SHOWN ARE IN INCHES